Unit: mm

TOSHIBA Field Effect Transistor Silicon P Channel MOS Type

SSM3J16FV

High Speed Switching Applications Analog Switch Applications

· Small package

Low on-resistance

 $: R_{on} = 8 \Omega \text{ (max) } (@V_{GS} = -4 \text{ V})$

 $R_{on} = 12 \Omega \text{ (max) (@VGS} = -2.5 \text{ V)}$

: $R_{on} = 45 \Omega \text{ (max) } (@V_{GS} = -1.5 \text{ V})$

Absolute Maximum Ratings (Ta = 25°C)

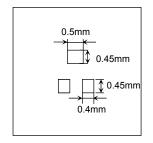
Characteristics		Symbol	Rating	Unit	
Drain-Source voltage		V _{DS}	-20	V	
Gate-Source voltage		V _{GSS}	±10	V	
Drain current	DC	I _D	-100	mA	
	Pulse	I _{DP}	-200		
Drain power dissipation (Ta = 25°C)		P _D (Note 1)	150	mW	
Channel temperature		T _{ch}	150	°C	
Storage temperature range		T _{stg}	-55~150	°C	

Note:

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Total rating, mounted on FR4 board (25.4 mm \times 25.4 mm \times 1.6 t, Cu Pad: 0.6 mm 2 \times 3)



1. 2±0.05 0.8±0.05 0.8±0.05 1. Gate VESM 2. Source 3. Drain

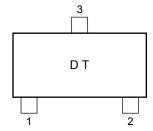
2-1L1B

Weight: 1.5mg

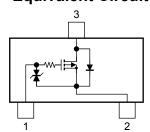
TOSHIBA

JEITA

Marking



Equivalent Circuit (top view)



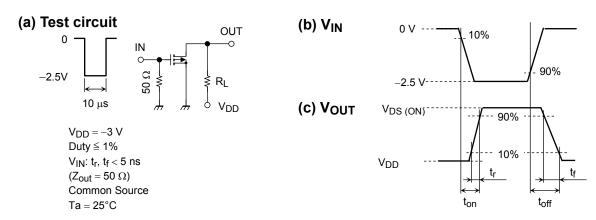
Handling Precaution

When handling individual devices (which are not yet mounted on a circuit board), ensure that the environment is protected against static electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

Electrical Characteristics (Ta = 25°C)

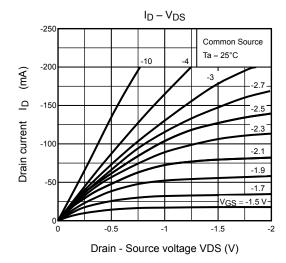
Characteristic		Symbol	Test Condition	MIN.	TYP.	MAX.	UNIT	
Gate leakage current		I _{GSS}	$V_{GS} = \pm 10 \text{ V}, V_{DS} = 0$	_	_	±1	μА	
Drain-Source breakdown voltage		V (BR) DSS	$I_D = -0.1 \text{ mA}, V_{GS} = 0$	-20	_	_	V	
Drain cut-off current		I _{DSS}	$V_{DS} = -20 \text{ V}, V_{GS} = 0$	_	_	-1	μА	
Gate threshold voltage		V_{th}	$V_{DS} = -3 \text{ V}, I_D = -0.1 \text{ mA}$	-0.6	_	-1.1	V	
Forward transfer admittance		Y _{fs}	$V_{DS} = -3 \text{ V}, I_D = -10 \text{ mA}$	25	_	_	mS	
Drain-Source on-resistance		R _{DS} (ON)	$I_D = -10 \text{ mA}, V_{GS} = -4 \text{ V}$	_	6	8		
			$I_D = -10 \text{ mA}, V_{GS} = -2.5 \text{ V}$	_	8	12	Ω	
			$I_D = -1 \text{ mA}, V_{GS} = -1.5 \text{ V}$	_	18	45		
Input capacitance		C _{iss}		_	11	_	pF	
Reverse transfer capacitance		C _{rss}	$V_{DS} = -3 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	_	3.7	_	pF	
Output capacitance		C _{oss}		_	10	_	pF	
Switching time	Turn-on time	t _{on}	$V_{DD} = -3 \text{ V}, I_{D} = -10 \text{ mA},$	_	130	_	- ns	
	Turn-off time	t _{off}	$V_{GS} = 0 \sim -2.5 \text{ V}$	_	190			

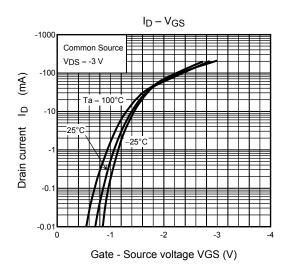
Switching Time Test Circuit

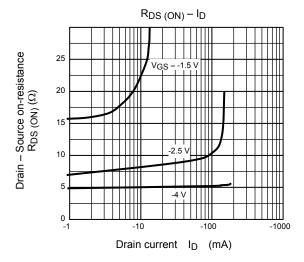


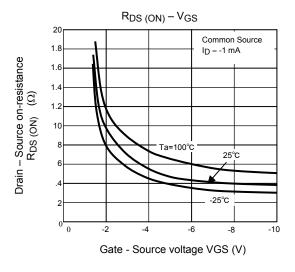
Precaution

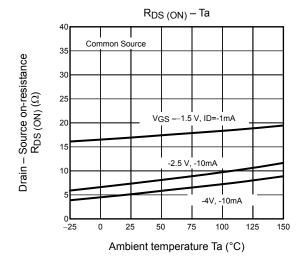
 V_{th} can be expressed as the voltage between the gate and source when the low operating current value is ID = $100~\mu A$ for this product. For normal switching operation, V_{GS} (on) requires a higher voltage than V_{th} and V_{GS} (off) requires a lower voltage than V_{th} . (The relationship can be established as follows: V_{GS} (off) $< V_{th} < V_{GS}$ (on).) Be sure to take this into consideration when using the device.

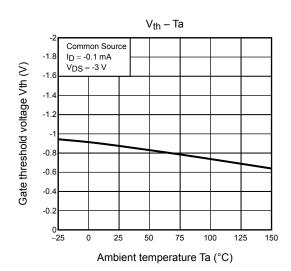




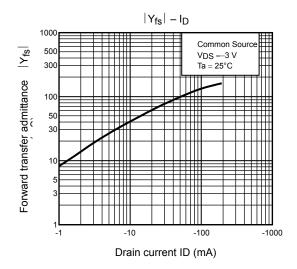


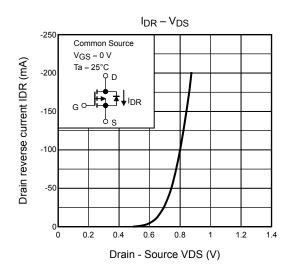


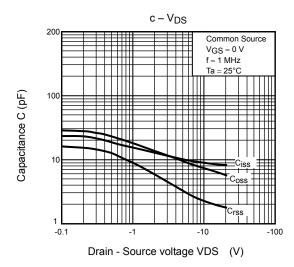


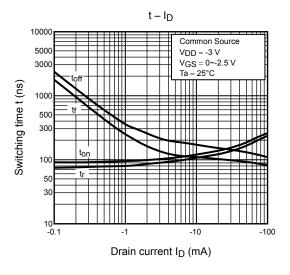


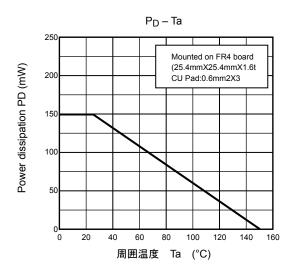
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20070701-EN GENERAL

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